NSN 5961-01-162-4615

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View Online at https://aerobasegroup.com/nsn/5961-01-162-4615 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **End Application:** 6625-01-022-5859 **Mounting Facility Quantity: Internal Configuration:** Field effect-dual gate Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 drain to source voltage and 200.0 drain to gate voltage **Current Rating Per Characteristic:** 9.00 amperes source cutoff current of standard range **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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